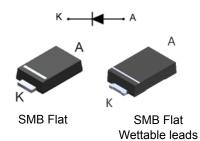


Automotive high voltage ultrafast rectifier



Features

- AEC-Q101 qualified
- Very low conduction losses
- · Negligible switching losses
- Low forward and reverse recovery times
- · High junction temperature
- ECOPACK2 or ECOPACK3 compliant component on demand

Description

The STTH110-Y, which is using ST's new 1000 V planar technology, is especially suited for switching mode base drive and transistor circuits.

The device is also intended for use as a free-wheeling diode in power supplies and other power switching applications in automotive K functions.



Product status link STTH110-Y

Product summary				
I _{F(AV)} 1 A				
V _{RRM}	1000 V			
T _j (max.)	175 °C			
V _F (typ.)	0.98 V			
T _{rr} (typ.)	52 ns			



1 Characteristics

Table 1. Absolute ratings (limiting values at T_i = 25 °C, unless otherwise specified)

Symbol	Para	meter	Value	Unit
V _{RRM}	Repetitive peak reverse	Repetitive peak reverse voltage		V
I _{F(AV)}	Average forward current	11=140 C 0 = 0.5		А
I _{FSM}	Forward surge current	t _p = 8.3 ms	20	А
T _{stg}	Storage temperature ran	Storage temperature range		°C
Tj ⁽¹⁾	Operating temperature r	Operating temperature range		°C

^{1.} $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-l)}	Junction to lead	20	°C/W

Table 3. Static electrical characteristic

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I_ (1)	L (1) Pavara ladian aument		\/ -\/	-		5	
IR ^(*)	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	V _R =V _{RRM}	-	1	50	μA
V _F ⁽²⁾	V-(2) Forward voltage drap		I _F =1 A	-		1.7	V
VF. /	Forward voltage drop	T _j = 150 °C	IF-I A	-	0.98	1.42	

- 1. Pulsetest: $tp = 5 \text{ ms}, \delta < 2\%$
- 2. Pulsetest: $tp = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 1.20 \text{ x } I_{F(AV)} + 0.225 I_{F^2(RMS)}$

Table 4. Dynamic electrical characteristics

Symbol	Parameter	Test conditions			Тур.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25 °C	I _F =0.5 A; I _{rr} =0.25 A; I _R =1 A	-	52	75	no
t _{fr}	Forward recovery time	T _i = 25 °C	I_F =1 A; $dI_{F/dt}$ = 50 A/ μ s; V_{FR} =2.70 V	-		300	ns
V _{FP}	Forward recovery voltage	1 1 25 0		-	10	15	V

DS10077 - Rev 2 page 2/8

V_F(V)

2.4

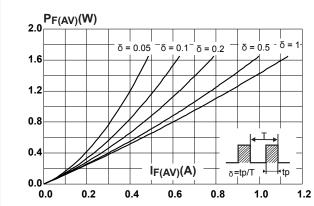
2.0

1.6



1.1 Electrical characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current



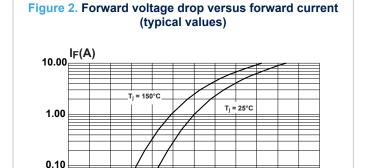


Figure 3. Forward voltage drop versus forward current (maximum values)

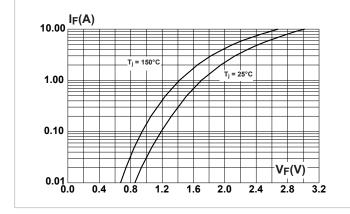


Figure 4. Relative variation of thermal impedance junction to lead versus pulse duration

1.2

0.8

0.01

0.4

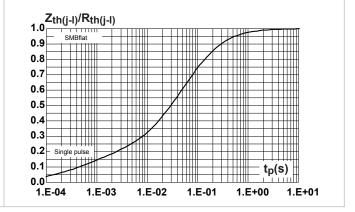


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

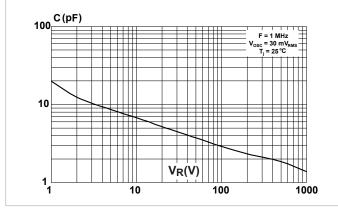
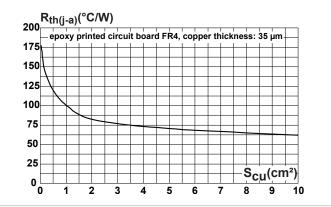


Figure 6. Thermal resistance junction to ambient versus copper surface under each lead



DS10077 - Rev 2 page 3/8



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SMB Flat package information

- Epoxy meets UL94, V0
- Lead-free package

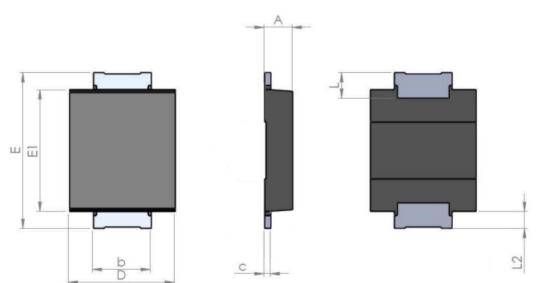


Figure 7. SMB Flat package outline

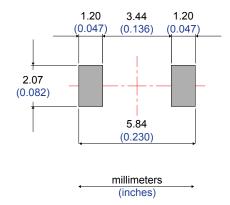
Table 5. SMB Flat mechanical data

	Dimensions							
Ref.		Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	0.90		1.10	0.035		0.043		
b	1.95		2.20	0.077		0.087		
С	0.15		0.40	0.006		0.016		
D	3.30		3.95	0.130		0.156		
E	5.10		5.60	0.200		0.220		
E1	4.05		4.60	0.159		0.181		
L	0.75		1.50	0.030		0.060		
L2		0.60			0.024			

DS10077 - Rev 2 page 4/8



Figure 8. Footprint recommendations, dimensions in mm (inches)



DS10077 - Rev 2 page 5/8



3 Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH110UFY	F110Y	SMBflat	50mg	5000	Tape and reel

DS10077 - Rev 2 page 6/8



Revision history

Table 6. Document revision history

Date	Version	Changes
05-Feb-2014	1	Initial release.
01-Mar-2022	2	Updated Section 2.1 SMB Flat package information.

DS10077 - Rev 2 page 7/8



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DS10077 - Rev 2 page 8/8